Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.165 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
D0-4
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Overall Width Across Flats:
0.430 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 working peak reverse voltage
Current Rating Per Characteristic:
20.00 amperes collector current, dc absolute
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0